



বিদ্যাসাগর বিশ্ববিদ্যালয়  
**VIDYASAGAR UNIVERSITY**  
**Question Paper**

**B.Sc. Honours Examinations 2022**

(Under CBCS Pattern)

**Semester - VI**

**Subject : ELECTRONICS**

**Paper : DSE 4-T**

**Basic VLSI Design**

**Full Marks : 40**

**Time : 2 Hours**

*Candidates are required to give their answers in their own words as far as practicable.*

*The figures in the margin indicate full marks.*

1. Answer any *four* questions. Each question carries five marks : 5×4=20
- (i) Draw stick diagram of a NAND gate. 5
  - (ii) What are the small channel geometry effect of MOSFET? 5
  - (iii) Differentiate between voltage scaling and field scaling. 5
  - (iv) Draw transfer characteristics of MOSFET and indicate different region of operation of MOSFET. 5
  - (v) Draw X-OR gate using pass transistor logic. 5
  - (vi) Write short notes on BiCOMOS. 5

2. Answer any *two* questions. Each question carries ten marks : 10×2=20

- (i) Write principle operation of SRAM using CMOS logic. 10
  - (ii) Design JK flip-flop using CMOS logic and explain its operation. 10
  - (iii) Write basic principle of CMOS inverter circuit. 10
  - (iv) Write short note on stable circuit using MOS. 10
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Vidyasagar University

**Or,**  
**Paper - DSE 4-T**  
**Nano Electronics**

Full Marks : 40

Time : 2 Hours

1. Answer any *four* questions. Each question carries five marks : 5×4=20
- (i) Discuss on quantum confinement effect in nanomaterials. 5
  - (ii) Write a short note on carbon nanotube. 5
  - (iii) Discuss briefly X-ray spectroscopy. 5
  - (iv) Mention the use of nanoparticles for biological application. 5
  - (v) Discuss the impact of nanotechnology on the environment. 5
  - (vi) Give a brief discussion on infrared detectors. 5
2. Answer any *two* questions. Each question carries ten marks : 10×2=20
- (i) Discuss the methods of bottom up and top down approaches of nano materials synthesis. 10
  - (ii) Explain the working principle of Raman spectroscopy. 10
  - (iii) Discuss the working principle of transmission electron microscopy (TEM). 10
  - (iv) (a) Explain the quantum confinement effect in nanomaterials.
  - (b) Discuss briefly on ballistic transport. 5+5
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**Or,**  
**Paper - DSE 4-T**  
**Embedded Systems**

Full Marks : 40

Time : 2 Hours

1. Answer any *four* questions. Each question carries five marks : 5×4=20
- (i) Write the requirements and applications of embedded systems. 2½+2½
  - (ii) Write applications of RISC and CISC microcontrollers. 2½+2½
  - (iii) Write different instruction sets used in AVR RISC microcontrollers. 5
  - (iv) Explain analog comparator. 5
  - (v) Describe system clock used in embedded system. 5
  - (vi) Explain serial peripheral interface. 5
2. Answer any *two* questions. Each question carries ten marks : 10×2=20
- (i) Explain architecture of AVR RISC microcontrollers. 10
  - (ii) Write embedded software design issues. 10
  - (iii) Write short note on analog-to-digital converter. 10
  - (iv) Write short note on universal synchronous and asynchronous serial receiver and transmitter (USART) 10
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**Or,**  
**Paper - DSE 4-T**  
**Biomedical Instrumentation**

Full Marks : 40

Time : 2 Hours

1. Answer any *four* questions. Each question carries five marks : 5×4=20
- (i) What is physiological transducer? Describe briefly. 2+3
  - (ii) Write down photoelectric transducer. 5
  - (iii) Write short note on MEMS based biosensors. 5
  - (iv) Write down the method of monitoring fetal heart rate. 5
  - (v) What is the function of blood gas analyzer? 5
  - (vi) Write down the use of microprocessors in medical instruments. 5
2. Answer any *two* questions. Each question carries ten marks : 10×2=20
- (i) Write down working principle of X-Ray machine. 10
  - (ii) Write short note on ECG. 10
  - (iii) Write short note on audiometer. 10
  - (iv) Write short note on spirometer. 10
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